

# MD1S THRU MD7S

## Miniature Glass Passivated Single Phase Surface Mount Bridge Rectifier

Reverse Voltage - 50 to 1000 V

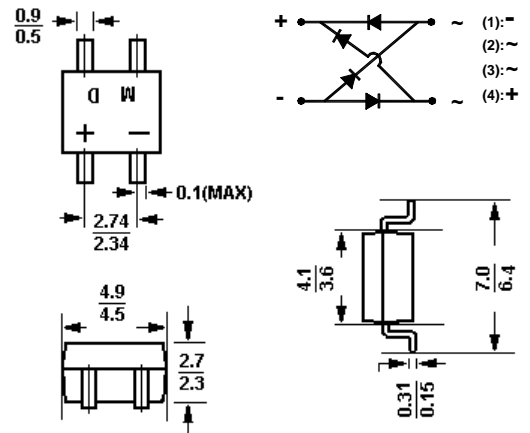
Forward Current - 0.5 A

### Features

- Surge overload rating: 30 amperes peak
- Ideal for printed circuit board
- Low leakage
- Reliable low cost construction utilizing molded
- Plastic package has Underwriters Laboratory Flammability Classification 94V-O

### Mechanical Data

- **Case:** MD-S, molded plastic.
- **Terminals:** Leads solderable per MIL-STD-202, method 208.
- **Mounting position:** Any.
- **Weight:** 0.008 ounce, 0.22 grams.
- **Polarity:** Color band denotes cathode



Dimensions in mm

### Absolute Maximum Ratings and Characteristics

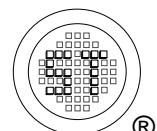
Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

|  | Symbols         | MD1S        | MD2S | MD3S | MD4S | MD5S | MD6S | MD7S | Units   |
|--|-----------------|-------------|------|------|------|------|------|------|---------|
| Maximum recurrent peak reverse voltage   | $V_{RRM}$       | 50          | 100  | 200  | 400  | 600  | 800  | 1000 | V       |
| Maximum RMS voltage  | $V_{RMS}$       | 35          | 70   | 140  | 280  | 420  | 560  | 700  | V       |
| Maximum DC blocking voltage  | $V_{DC}$        | 50          | 100  | 200  | 400  | 600  | 800  | 1000 | V       |
| Maximum average forward rectified current<br>See Fig .1<br>On glass epoxy P.C.B <sup>2)</sup><br>On aluminum substrate <sup>3)</sup> | $I_{(AV)}$      | 0.5<br>0.8  |      |      |      |      |      |      | A       |
| Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)                                     | $I_{FSM}$       | 30          |      |      |      |      |      |      | A       |
| Maximum forward voltage at 0.4A DC   | $V_F$           | 1.0         |      |      |      |      |      |      | V       |
| Maximum reverse current<br>@ $T_A = 25^\circ C$<br>at rated DC blocking voltage<br>@ $T_A = 125^\circ C$                             | $I_R$           | 5.0<br>500  |      |      |      |      |      |      | $\mu A$ |
| Typical junction capacitance <sup>1)</sup>   | $C_J$           | 15          |      |      |      |      |      |      | pF      |
| Typical thermal resistance <sup>3)</sup>   | $R_{\theta JA}$ | 76          |      |      |      |      |      |      | °C/W    |
| Typical thermal resistance <sup>2)</sup>   | $R_{\theta JL}$ | 20          |      |      |      |      |      |      | °C/W    |
| Operating and storage temperature range  | $T_J, T_{Stg}$  | -55 to +150 |      |      |      |      |      |      | °C      |

<sup>1)</sup> Measured at 1 MHz and applied  $V_r = 4$ volts.

<sup>2)</sup> On glass epoxy P.C.B. mounted on 0.05 x 0.05" (1.3 x 1.3 mm) pads.

<sup>3)</sup> On aluminum substrate P.C.B. with an area of 0.8 x 0.8" (20 x 20mm) mounted on 0.05 x 0.05" (1.3 x 1.3mm) solder pad.



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